

# PNP Switching Transistor MMBT4403M3T5G

The MMBT4403M3T5G device is a spin-off of our popular SOT-23 three-leaded device. It is designed for general purpose switching applications and is housed in the SOT-723 surface mount package. This device is ideal for low-power surface mount applications where board space is at a premium.

#### **Features**

- Reduces Board Space
- This is a Halide-Free Device
- This is a Pb-Free Device

# **MAXIMUM RATINGS**

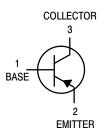
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	-40	Vdc
Collector-Base Voltage	$V_{CBO}$	-40	Vdc
Emitter - Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	-600	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) T <sub>A</sub> = 25 °C Derate above 25 °C	P <sub>D</sub>	265 2.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	470	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25 °C Derate above 25 °C	P <sub>D</sub>	640 5.1	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	195	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.



#### MARKING DIAGRAM



SOT-723 CASE 631AA STYLE 1



AG M = Specific Device Code

= Date Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBT4403M3T5G	SOT-723 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25 \, ^{\circ}C$ unless otherwise noted)

Chara	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Collector - Emitter Breakdown Voltage (Note	V <sub>(BR)CEO</sub>	-40	_	Vdc		
Collector-Base Breakdown Voltage	$(I_C = -0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)CBO</sub>	-40	-	Vdc	
Emitter-Base Breakdown Voltage	$(I_E = -0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	-5.0	-	Vdc	
Base Cutoff Current (V <sub>CE</sub> = -35 Vdc, V <sub>EB</sub> =	-0.4 Vdc)	I <sub>BEV</sub>	-	-0.1	μAdc	
Collector Cutoff Current (V <sub>CE</sub> = -35 V	/dc, V <sub>EB</sub> = -0.4 Vdc)	I <sub>CEX</sub>	-	-0.1	μAdc	
ON CHARACTERISTICS						
$\begin{array}{c} \text{DC Current Gain} \\ & (I_C = -0.1 \text{ mAdc},  V_{CE} = -1.0 \text{ Vdc}) \\ & (I_C = -1.0 \text{ mAdc},  V_{CE} = -1.0 \text{ Vdc}) \\ & (I_C = -10 \text{ mAdc},  V_{CE} = -1.0 \text{ Vdc}) \\ & (\text{Note 3}) & (I_C = -150 \text{ mAdc},  V_{CE} = -2.0 \text{ Vdc}) \\ & (\text{Note 3}) & (I_C = -500 \text{ mAdc},  V_{CE} = -2.0 \text{ Vdc}) \end{array}$	)	h <sub>FE</sub>	30 60 100 100 20	- - - 300 -	-	
Collector – Emitter Saturation Voltage (Note $(I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc})$ $(I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc})$	V <sub>CE(sat)</sub>	- -	-0.4 -0.75	Vdc		
Base – Emitter Saturation Voltage (Note 3) $ (I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc}) $ $ (I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc}) $	V <sub>BE(sat)</sub>	-0.75 -	-0.95 -1.3	Vdc		
SMALL-SIGNAL CHARACTERISTICS						
Current-Gain – Bandwidth Product ( $I_C = -20$	fT	200	-	MHz		
Collector-Base Capacitance (V <sub>CB</sub> = −10 V	/dc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>cb</sub>	-	8.5	pF	
Emitter-Base Capacitance (V <sub>BE</sub> = -0.5 \	/dc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>eb</sub>	_	30	pF	
Input Impedance ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} =$	h <sub>ie</sub>	1.5	15	kΩ		
Voltage Feedback Ratio (I <sub>C</sub> = −1.0 m/s	h <sub>re</sub>	0.1	8.0	X 10 <sup>-4</sup>		
Small-Signal Current Gain (I <sub>C</sub> = -1.0 m/	h <sub>fe</sub>	60	500	-		
Output Admittance ( $I_C = -1.0 \text{ mAdc}$ , $V_{CE} =$	h <sub>oe</sub>	1.0	100	μMhos		
SWITCHING CHARACTERISTICS						
Delay Time	(V <sub>CC</sub> = -30 Vdc, V <sub>EB</sub> = -2.0 Vdc,	t <sub>d</sub>	_	15	no	
Rise Time	I <sub>C</sub> = -150 mAdc, I <sub>B1</sub> = -15 mAdc)	t <sub>r</sub>	_	20	ns	
Storage Time	(V <sub>CC</sub> = −30 Vdc, I <sub>C</sub> = −150 mAdc,	t <sub>s</sub>	_	225	ns	
Fall Time	I <sub>B1</sub> = I <sub>B2</sub> = −15 mAdc)	t <sub>f</sub>	-	30	1115	

<sup>3.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

### **SWITCHING TIME EQUIVALENT TEST CIRCUIT**

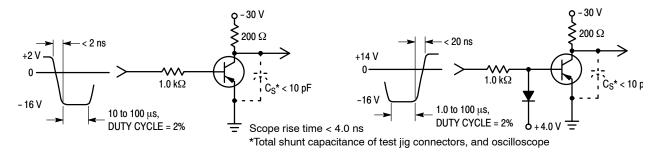


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

#### STATIC CHARACTERISTICS

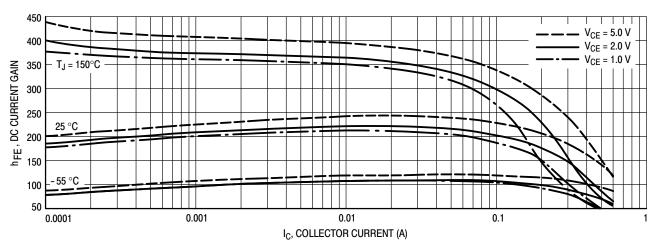


Figure 3. DC Current Gain

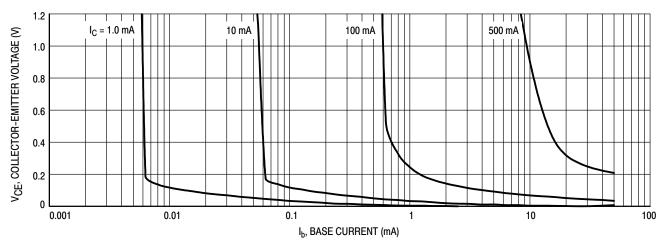


Figure 4. Collector Saturation Region

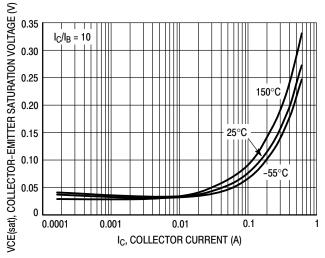


Figure 5. Collector-Emitter Saturation Voltage vs. Collector Current

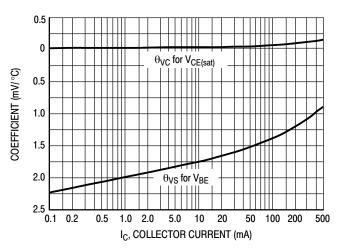


Figure 6. Temperature Coefficients

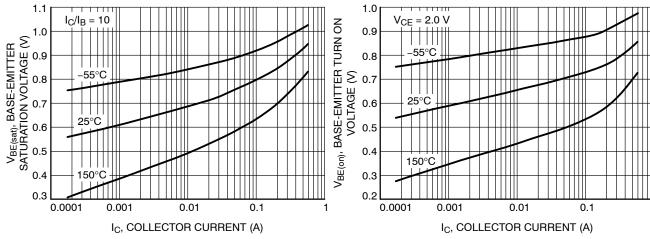


Figure 7. Base-Emitter Saturation Voltage vs.
Collector Current

Figure 8. Base-Emitter Turn On Voltage vs. Collector Current

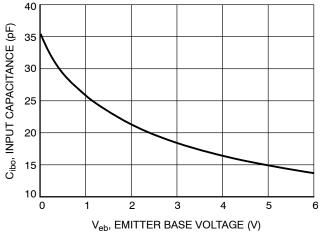


Figure 9. Input Capacitance vs. Emitter Base Voltage

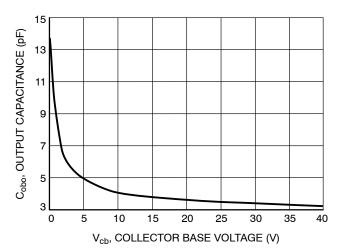


Figure 10. Output Capacitance vs. Collector Base Voltage

# **REVISION HISTORY**

Revision	Description of Changes	Date
1	Rebranded the Data Sheet to <b>onsemi</b> format.	6/24/2025



MILLIMETERS

 $N\square M$ .

0.50

0.21

0.31

0.12

1.20

0.80

0.40 BSC

1.20

0.29 REF





#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

**DATE 24 JAN 2024** 

MAX.

0.55

0.27

0.37

0.17

1.25

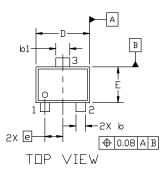
0.85

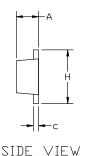
1.25

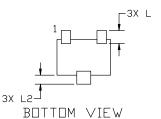
0.25

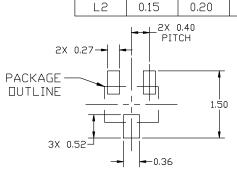
#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.









DIM

Α

b

b1

 $\subset$ D

Ε

е Н

L

MIN.

0.45

0.15

0.25

0.07

1.15

0.75

1.15

#### RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

#### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. GATE
<ol><li>EMITTER</li></ol>	2. N/C	2. ANODE	2. CATHODE	<ol><li>SOURCE</li></ol>
<ol><li>COLLECTOR</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>ANODE</li></ol>	<ol><li>DRAIN</li></ol>

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DESCRIPTION:	SOT-723 1.20x0.80x0.50, 0.40P		PAGE 1 OF 1	

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